# NCE N-Channel Enhancement Mode Power MOSFET

#### **DESCRIPTION**

The NCE6020L uses advanced trench technology and design to provide excellent  $R_{\text{DS}(\text{ON})}$  with low gate charge. It can be used in a wide variety of applications.

#### **GENERAL FEATURES**

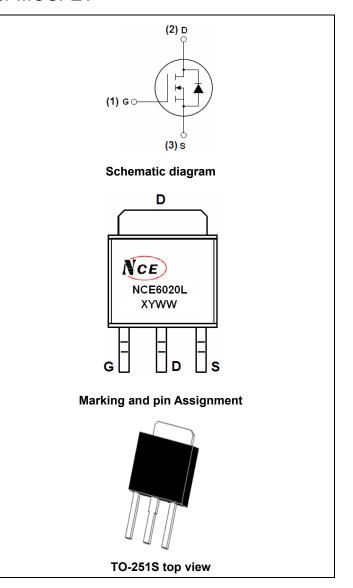
- $V_{DS}$  =60V, $I_{D}$  =20A  $R_{DS(ON)}$  <45m $\Omega$  @  $V_{GS}$ =10V
- High density cell design for ultra low Rdson
- Fully characterized Avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

#### **Application**

- Power switching application
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

100% UIS TESTED!

100% ΔVds TESTED!



#### **Package Marking And Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6020L	NCE6020L	TO-251S	-	-	-

#### Absolute Maximum Ratings (TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	20	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	14	Α
Pulsed Drain Current	I <sub>DM</sub>	60	Α
Maximum Power Dissipation	P <sub>D</sub>	40	W
Derating factor		0.27	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	72	mJ



# http://www.ncepower.com

# NCE6020L

Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$
Thermal Characteristic			
Thermal Resistance.Junction-to-Case(Note 2)	Raic	3.7	°C/W

#### Electrical Characteristics (TA=25°C unless otherwise noted)

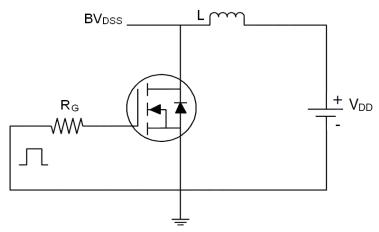
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u>.</u>					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	=0V -		1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	1	2.1	3	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	37	45	mΩ
Forward Transconductance	<b>G</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =4.5A	11	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ 20\/\/ 0\/	-	500	-	PF
Output Capacitance	Coss	$V_{DS}$ =30V, $V_{GS}$ =0V, F=1.0MHz	-	60	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WIDZ	-	25	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $R_L$ =6.7 $\Omega$	-	2.6	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{G}$ =3 $\Omega$	-	16.1	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	2.3	-	nS
Total Gate Charge	Qg	\/ -49\/  -45A	-	12		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =48V, $I_{D}$ =15A, $V_{GS}$ =10V	-	4.1		nC
Gate-Drain Charge	$Q_{gd}$	VGS=10V	-	4.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	20	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	-	35	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs(Note3)	-	53	-	nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

### Notes:

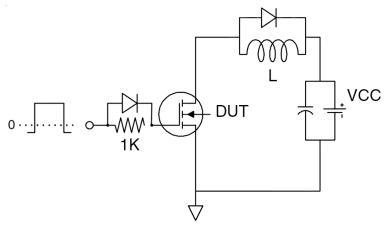
- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25  $^{\circ}$ C,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$

# **Test circuit**

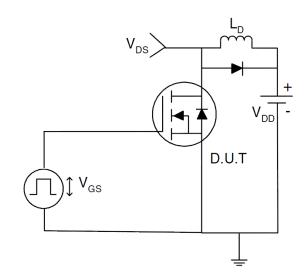
# 1) E<sub>AS</sub> test Circuits



# 2) Gate charge test Circuit:



# 3) Switch Time Test Circuit:





### TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)

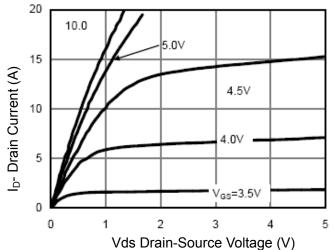
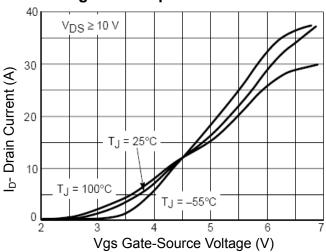


Figure 1 Output Characteristics



**Figure 2 Transfer Characteristics** 

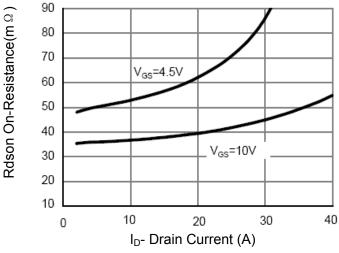


Figure 3 Rdson- Drain Current

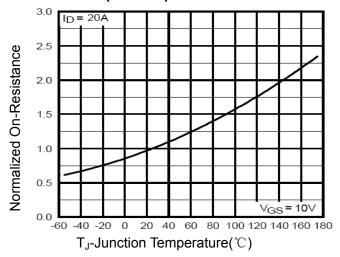


Figure 4 Rdson-JunctionTemperature

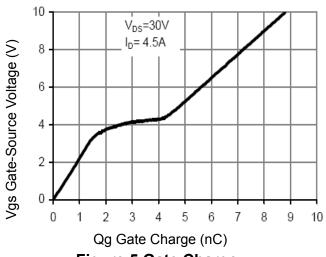


Figure 5 Gate Charge

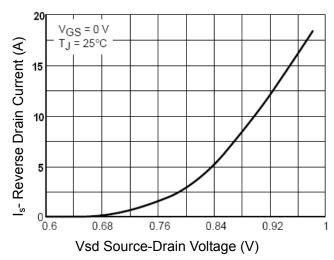


Figure 6 Source- Drain Diode Forward

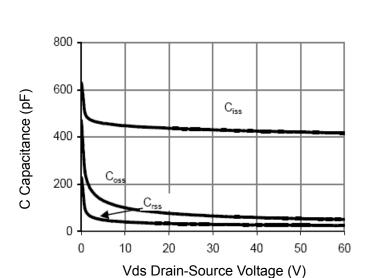


Figure 7 Capacitance vs Vds

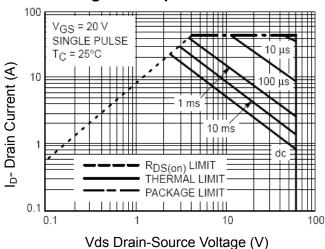


Figure 8 Safe Operation Area

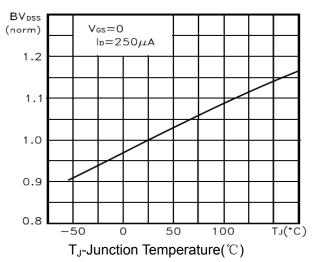


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

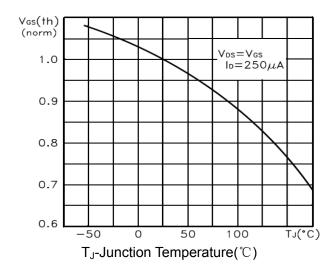


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature

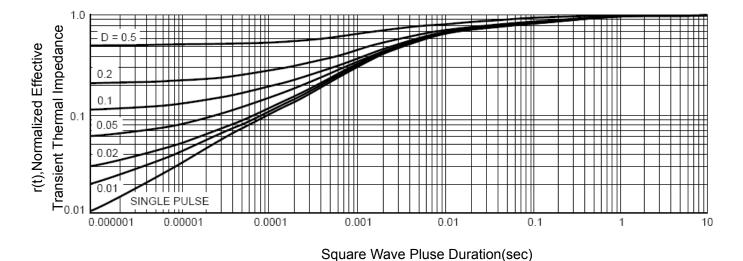
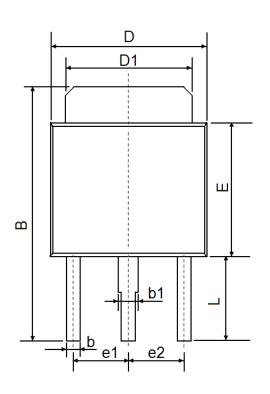
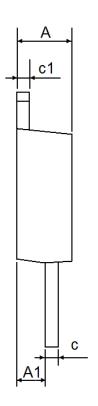


Figure 11 Normalized Maximum Transient Thermal Impedance

# **TO-251S Package Information**





Symbol	Dimensions I	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	2.250	2.350	0.089	0.093	
A1	1.150	1.250	0.045	0.049	
В	10.200	10.800	0.402	0.425	
b	0.550	0.650	0.022	0.026	
b1	0.750	0.850	0.030	0.033	
С	0.480	0.540	0.019	0.021	
c1	0.480	0.540	0.019	0.021	
D	6.400	6.600	0.252	0.260	
D1	5.250	5.350	0.207	0.211	
E	5.400	5.600	0.213	0.220	
e1	2.300 TYP		0.091 TYP		
e2	2.300 TYP		0.091 TYP		
L	3.300	3.700	0.130	0.146	

NCE6020L

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